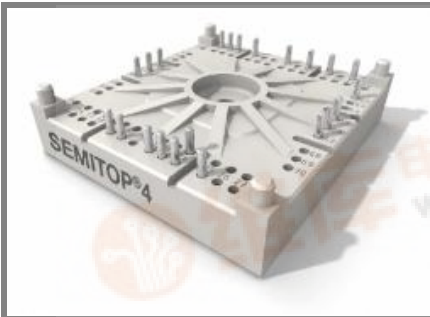


SK 50 DGDL 126 T



SEMISTOP® 4

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SK 50 DGDL 126 T

Target Data

Features

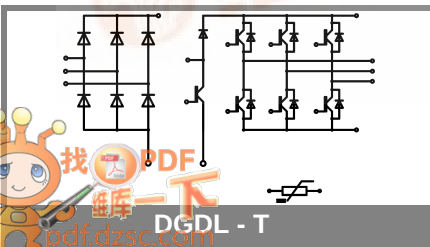
- One screw mounting module
- Fully compatible with SEMISTOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench IGBT technology
- CAL technology free-wheeling diode
- Integrated NTC temperature sensor

Typical Applications

- Inverter up to 28 kVA
- Typ. motor power 15 kW

1) $V_{ce,sat}$, V_f = chip level value

2) For IGBT chopper diagrams please refer to SK35DGDL126T

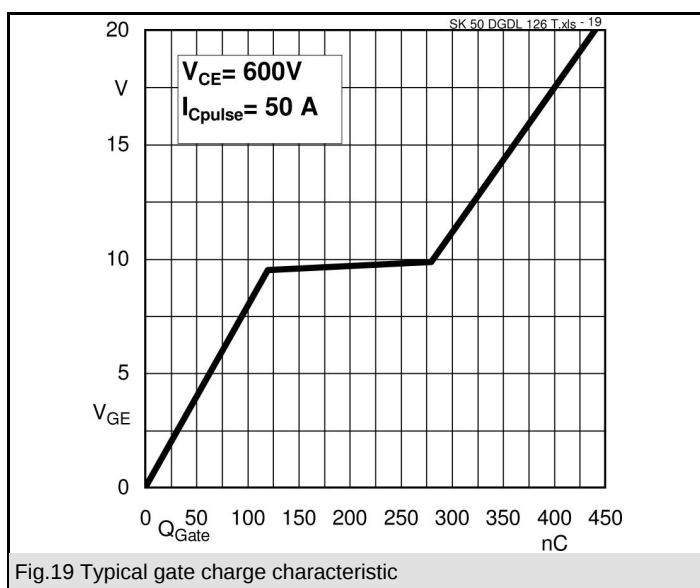
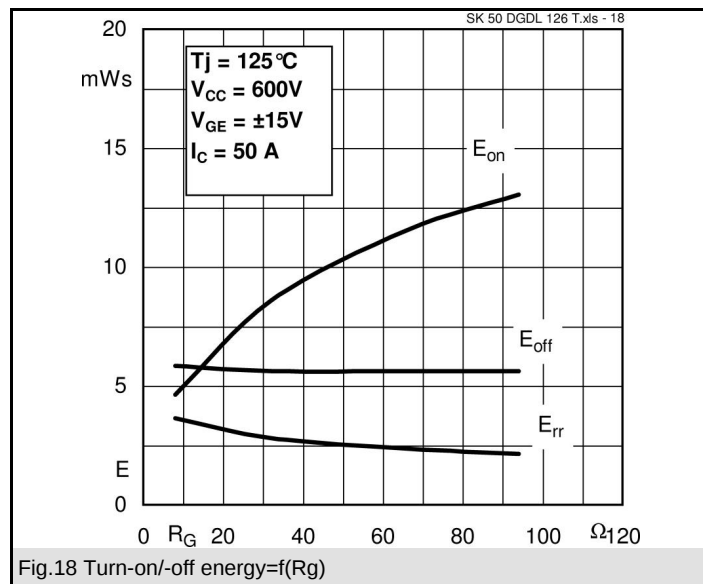
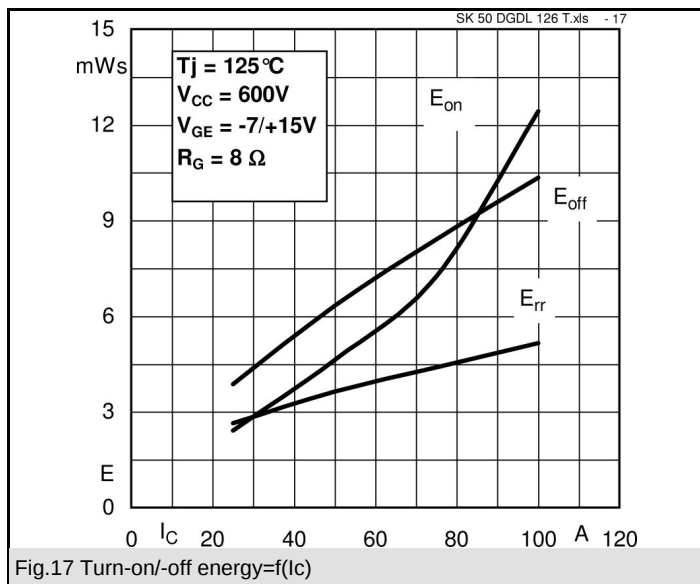
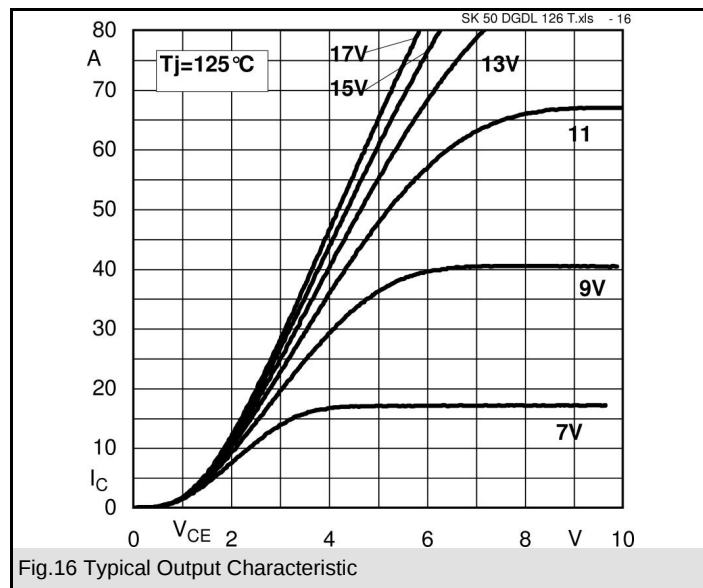
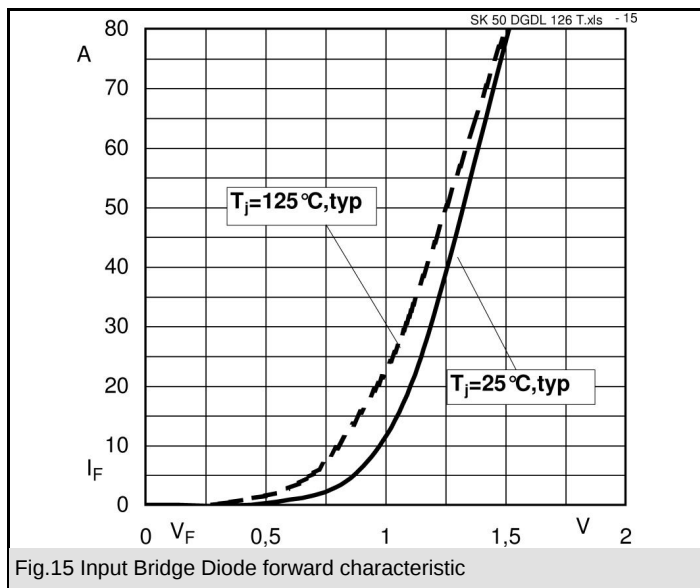


Absolute Maximum Ratings		Ts = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter. For IGBT chopper maximum ratings, please refer to SK35DGDL126T			
V_{CES}	$T_s = 25 (70) ^\circ C$	1200	V
I_C	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	68 (52)	A
I_{CRM}		100	A
V_{GES}		± 20	V
T_j		-40 ... +150	$^\circ C$
Diode - Inverter,Chopper			
I_F	$T_s = 25 (70) ^\circ C$	62 (46)	A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}, t_p = 1 \text{ ms}$	100	A
T_j		-40 ... +150	$^\circ C$
Rectifier			
V_{RRM}	$T_s = 70 ^\circ C$	1600	V
I_F	$t_p = 10 \text{ ms}, \sin 180 ^\circ, T_j = 25 ^\circ C$	45	A
I_{FSM} / I_{TSM}	$t_p = 10 \text{ ms}, \sin 180 ^\circ, T_j = 25 ^\circ C$	700	A
I_t^2	$t_p = 10 \text{ ms}, \sin 180 ^\circ, T_j = 25 ^\circ C$	2400	A ² s
T_j		-40 ... +150	$^\circ C$
T_{sol}	Terminals, 10 s	260	$^\circ C$
T_{stg}		-40 ... +125	$^\circ C$
V_{isol}	AC, 1 min. / 1 s	2500 / 3000	V

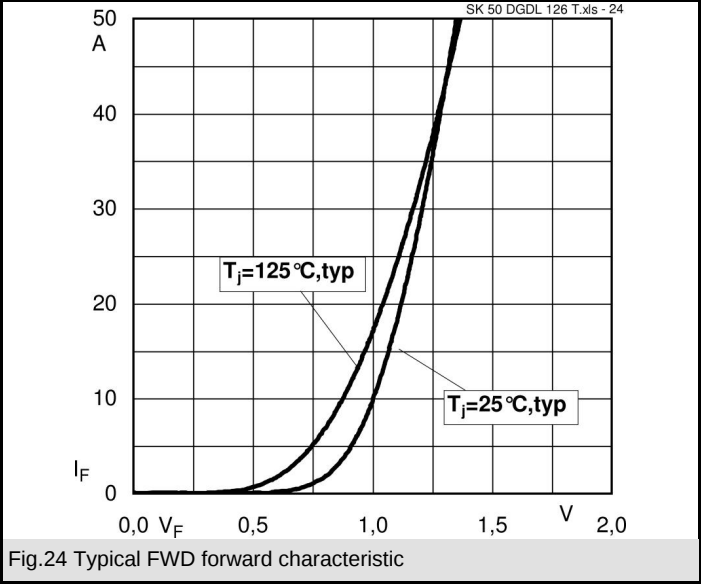
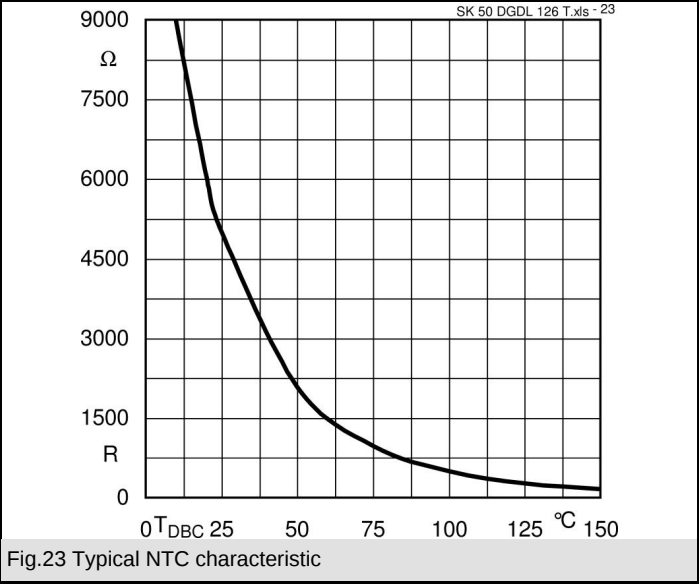
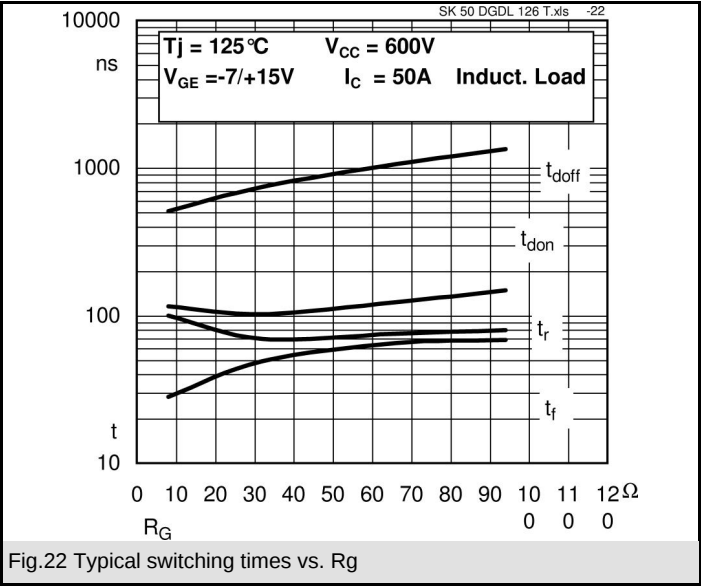
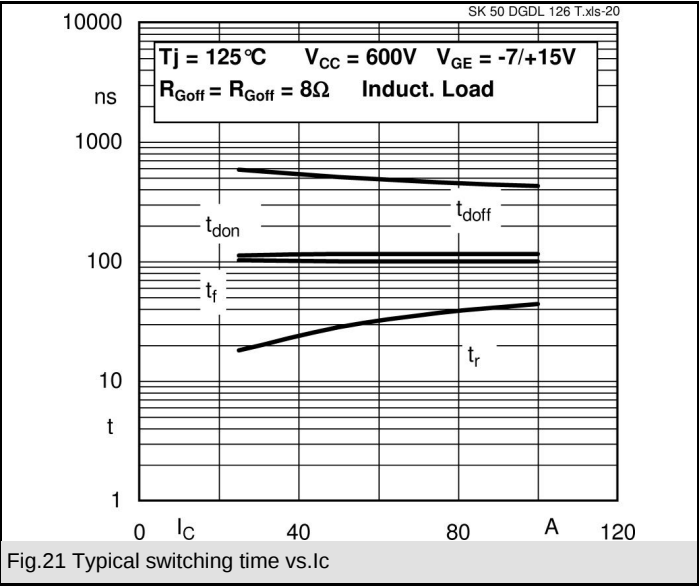
Characteristics		Ts = 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter. For IGBT chopper electrical characteristics, please refer to SK35DGDL126T					
V_{CEsat}	$I_C = 50 \text{ A}, T_j = 25 (125) ^\circ C$		1,7 (2)	2,15 (2,45)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 2 \text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25 ^\circ C (125) ^\circ C$		1 (0,9)	1,2 (1,1)	V
r_T	$T_j = 25 ^\circ C (125) ^\circ C$		14 (22)	19 (27)	mΩ
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		3,7		nF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,18		nF
C_{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,16		nF
$R_{th(j-s)}$	per IGBT		0,6		K/W
$t_{d(on)}$	under following conditions		115		ns
t_r	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		28		ns
$t_{d(off)}$	$I_C = 50 \text{ A}, T_j = 125 ^\circ C$		509		ns
t_f	$R_{Gon} = R_{Goff} = 8 \Omega$		100		ns
E_{on}	inductive load		4,6		mJ
E_{off}			6,3		mJ
Diode - Inverter,Chopper					
$V_F = V_{EC}$	$I_F = 50 \text{ A}, T_j = 25 (125) ^\circ C$		1,35 (1,35)		V
$V_{(TO)}$	$T_j = 25 ^\circ C (125) ^\circ C$		0,95 (0,85)		V
r_T	$T_j = 25 ^\circ C (125) ^\circ C$		8 (10)		mΩ
$R_{th(j-s)}$	per diode		1		K/W
I_{RRM}	under following conditions		30		A
Q_{rr}	$I_F = 50 \text{ A}, V_R = 600 \text{ V}$		10		μC
E_{rr}	$V_{GE} = 0 \text{ V}, T_j = 125 ^\circ C$		3,6		mJ
	$di_F/dt = 500 \text{ A/}\mu\text{s}$				
Diode - Rectifier					
V_F	$I_F = 35 \text{ A}, T_j = 25 ^\circ C$		1,1		V
$V_{(TO)}$	$T_j = 150 ^\circ C$		0,8		V
r_T	$T_j = 150 ^\circ C$		11		mΩ
$R_{th(j-s)}$	per diode		0,9		K/W
Temperatur sensor					
R_{ts}	5 %, $T_r = 25 (100) ^\circ C$		5000(493)		Ω
Mechanical data					
w			60		g
M_s	Mounting torque		3,5		Nm



SK 50 DGD L 126 T

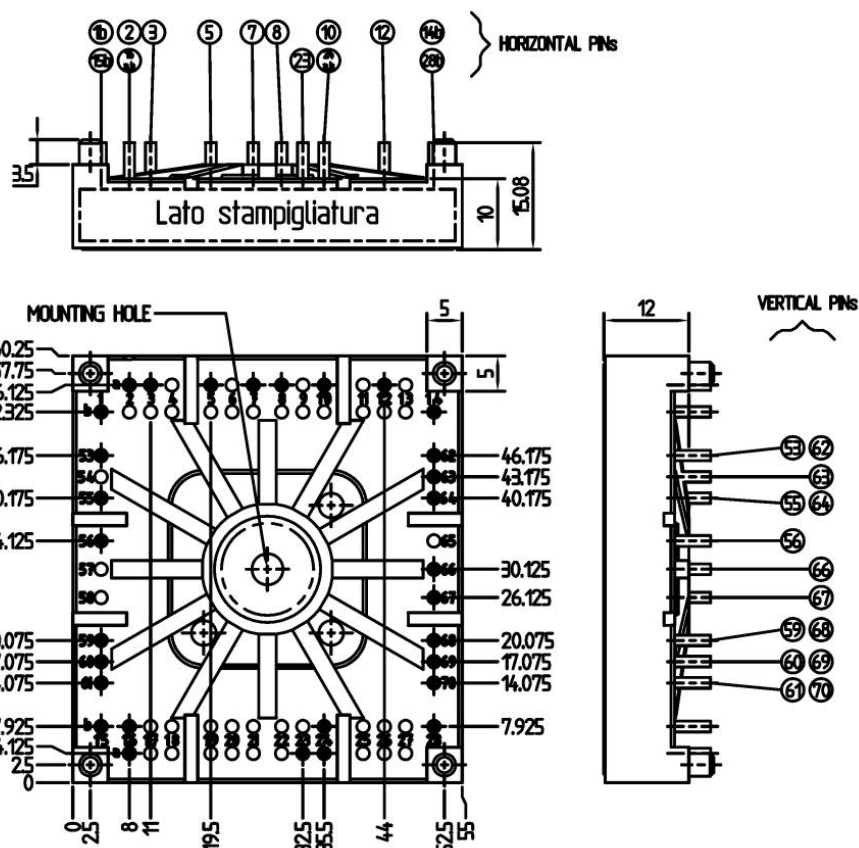


SK 50 DGDL 126 T

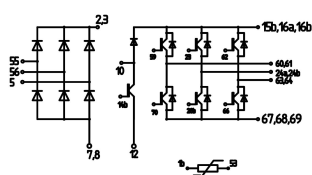


SK 50 DGDL 126 T

Dimensions in mm



Case T 75 (Suggested hole diameter for the solder pins in the circuit board: 2mm. Suggested hole diameter for the mounting pins in the circuit board: 3,6mm)



Case T 75 (pin without letter refers to row "a", unless otherwise specified)

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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